ROCHESTER INSTITUTE OF TECHNOLOGY MICROELECTRONIC ENGINEERING

RIT CHEMICAL SENSORS

Dr. Lynn Fuller, Ellie Brion, Ellen Sedlack

Dr. Fuller's Webpage: <u>http://www.rit.edu/~lffeee</u>

Microelectronic Engineering Rochester Institute of Technology 82 Lomb Memorial Drive Rochester, NY 14623-5604 Tel (585) 475-2035 Fax (585) 475-5041 Email: Lynn.Fuller@rit.edu Program webpage: http://www.microe.rit.edu

Rochester Institute of Technology Microelectronic Engineering

10-1-2011 Chemical_Sensors.ppt

© August 27, 2010 Dr. Lynn Fuller



CHEMIRESISTOR

Simple interdigitated electrodes coated with a chemically sensitive layer that changes the resistance in response to a few ppm of some (or many) chemicals



For example: carbon black mixed with polymer, the polymer swells breaking some of the carbon black connections increasing resistance of the sensor Resistor with 25µm gaps 25µm length 7250µm width

MODELING OF PARALLEL RESISTANCE CHANGE

If each resistor is identical with value equal to 400 ohms, what is the total resistance?

Answer 20 ohms

If two of the resistors in each row open circuits, what is the total resistance?

Answer 40 ohms

If two resistors in one row open circuits, what is the total resistance?

Answer 22.22 ohms or 11%

Rochester Institute of Technology Microelectronic Engineering

© August 27, 2010 Dr. Lynn Fuller

MODELING OF SERIES RESISTANCE CHANGE

If each resistor is identical with value equal to 400 ohms, what is the total resistance?

Answer 500 ohms

If two resistors in each row open circuits, what is the total resistance?

Answer 1000 ohms

If two resistors in one row open circuits, what is the total resistance?

Answer 600 ohms or 20%

Rochester Institute of Technology Microelectronic Engineering

© August 27, 2010 Dr. Lynn Fuller

SUMMARY OF MODELING

Series architecture with coatings whose resistance increases in the presence of some chemical being detected gives more sensitivity

Parallel architecture with coatings whose resistance decreases in the presence of some chemical being detected gives more sensitivity.

If the coating is perfectly uniform and responds uniformly then both architecture approaches give identical results.



Rochester Institute of Technology

Microelectronic Engineering

© August 27, 2010 Dr. Lynn Fuller

DEFINITION OF TERMS

ISE – Ion Sensitive electrodes

ISFET – Ion Sensitive Field Effect Transistor

Ionophore – compounds that allow specific ions to move through a membrane that they otherwise would not be able to pass through.

Oligomer – low molecular weight monomers often used with photocurable polymers Polymer- major substance in a coating film, gives the film strength

Permselectivity – intrinsic ion selectivity of the polymer film itself

- Plasticizer increases the plasticity of a substance, making it more flexible, prevent cracking,
- Solvent any substance that dissolves another substance. Allows the substance to flow for coating purposes.

Phthalates – one type of plasticizer commonly used but is a Teratogen (causes birth defects) restricted use since 1976 in Europe

UV Blocker – blocks ultraviolet radiation

Rheological Properties – flow characteristics

Photoinitiator – causes cross linking in the presents of light

Crosslinker – used with low molecular weight monomers, causes cross linking

COATING TO DETECT ETHANOL

- 2 μm of (3,4-polyethylenedioxythiopene-polystyrenesulfonate) PEDOT polymer is applied to interdigitated electrodes and cured at 100 °C for 30 minutes
- PEDOT is a conductive polymer which upon exposure to ethanol vapors, will adsorb the ethanol causing the polymer to swell which results in a measurable change of resistance across the electrodes





© August 27, 2010 Dr. Lynn Fuller









FINISHED WAFERS OF CHEMICAL SENSORS



Rochester Institute of Technology Microelectronic Engineering

© August 27, 2010 Dr. Lynn Fuller

WAFERS OF SENSORS CUT (SOME REMOVED)





Ellen Sedlack

Rochester Institute of Technology

Microelectronic Engineering

© August 27, 2010 Dr. Lynn Fuller



COMPLETED ELECTRODES



COMPLETED ELECTRODES



Left: Sensor chip (no coating) with clip on pins Right: Sensor chip with solder connections

> Rochester Institute of Technology Microelectronic Engineering

> > © August 27, 2010 Dr. Lynn Fuller

page 18

CHEMICAL SENSOR USING SERIES ARCHITECTURE



GAS CONCENTRATION CALCULATOR

| Rochester Ins | titute of Technol | ogy | | | 20-Mar-06 | | | |
|----------------------|---|----------------|---|-------------------------|---------------------|--------------|--|-------------|
| Microe lectro | nic Engineering | | | | Dr. Lynn Fuller | | | |
| | | | | | | | | |
| <u>Concentration</u> | n Calculations: | <u> </u> | <u> </u> | | | | _ | |
| When testing of | chemical sensors i | t is important | to know the c | oncentration | of the chemical to | determine | _ | |
| the fellowing of | For chemicals in | al are availab | ie as a líquid bi | ul evaporate | in a volume of air, | one can use | | |
| the following et | | | | | | | | |
| Concentratio | n (in ppm) = [We | iaht (ma) / C | hamber volu | me (m ³)] X | | | BAC = Blood Alcoho | ol Concent |
| | IVolume of | one mole o | of air (L/mole) | / Mole cula | r weight of samp | le (g/mole)] | BAC = wt. ln gm of the second secon | ethanol/10 |
| | | | | | | | BAC = wt. In gm of ethanol/21 | |
| To use this spi | read sheet input va | lues in the w | hite boxes and | results will | be displayed in pur | ple boxes | | |
| | | | | | | | | |
| | | | volum | e of liquid = | 0.0002 | ml | Chamber Volume = | 0.2 |
| Example: | 3 | | <u>if liquid = volum</u> | nex density | 0.1632 | mg | | 0.00016 |
| Chamber of 1 I | Chamber of 1 Liter = 1000 cm ³ = 0.001 Volume of air = 24.45 L/mole | | .001 m [°] Chamber volume = Volume of air = | | 0.00025 | m | _ | 210 |
| Volume of air = | | | | | 24.45 | | _ | 0.13/08 |
| note: valid at T | -25°C and P-760 | l mm Ha | molecular | wt sample= | 46.06952 | g/more | Ev: 0.0002ml ethan | nl in 250 m |
| | | | Concentratio | n in pom = | 346 | ppm | which is equivalent t | o 346 ppm |
| Data: | | | | | | | | |
| Chemical | Chemical | Molecular | Density | Select | | | | |
| name | formula | weight | Kg/m ³ | one entry = | 1, others = 0 | | | |
| methanol | CH₃OH | 32.04243 | 810 | 0 | | | | |
| ethanol | CH₃CH₂OH | 46.06952 | 816 | 1 | | | | |
| 2-propanol | CH3CH2CH2OH | 60.09661 | 804.13 | 0 | | | | |
| acetone | | 58.08 | 784.58 | 0 | | | | |
| | | | 10 1100 | | | | | |
| Reference: http | o://www.ilpi.com/m | sds/ref/conce | entration.html | | | | | |
| | | | | | | | | 1 |
| | | | © August 27 | 7,2010 Dr | . Lynn Fuller | | 70 20 | |

POLYMERS USED TO MAKE SENSORS

 Air Plane Glue

 Bond adhesives Co., Multipurpose Adhesive 527

 From the MSDS:
 Nitrocellulose (polymer)

 Trade Secret (plasticizer)
 X%

 Acetone (solvent)
 66%

 Isopropanol (solvent)
 7%

 Propylene Glycol Monoethyl Ether (rheological properties)
 4%

Cellulose Acetate Solution

| Nitrocellulose (polymer) | 10% |
|----------------------------------|---|
| Di butyl Phthalate (plasticizer) | 1% |
| Camphor (aromatic) | 5% |
| Benzophenone-1 (UV Blocker) | 1% |
| Toluene (solvent) | 5% |
| Butyl acetate (solvent) | 25% |
| Ethyl Acetate (solvent) | 45% |
| Isopropyl Alcohol (solvent) | 5% |
| | Nitrocellulose (polymer) Di butyl Phthalate (plasticizer) Camphor (aromatic) Benzophenone-1 (UV Blocker) Toluene (solvent) Butyl acetate (solvent) Ethyl Acetate (solvent) Isopropyl Alcohol (solvent) |

© August 27, 2010 Dr. Lynn Fuller

MECHANISM OF POLYMER SWELLING

Solvents interact with the polymer, plasticizer or other additives in the film causing swelling. For example nail polish and airplane glue have the same base polymer, Nitrocellulose, which swells in the presence of acetone and both show acetone sensitivity. Nail polish does not show sensitivity to alcohol but air plane glue does so one explanation is that the alcohol sensitivity in air plane glue is due to the type of plasticizer used.

Rochester Institute of Technology Microelectronic Engineering

© August 27, 2010 Dr. Lynn Fuller

AIR PLANE GLUE / CARBON BLACK TEST RESULTS







ELLIE BRION







ELECTRODE ARRAYS AVAILABLE FROM RIT

ELECTRODE ARRAYS AVAILABLE FROM RIT

| MODEL # | METAL MATERIAL | SUBSTRATE MATERIAL | TYPE | WIDTH | SPACE | LENGTH | NUMBER OF ELEMENTS | PRICE EACH |
|--|--|--|--|----------------------------------|----------------------------------|--------------------------------------|---|--|
| Ta50-10-37Si | Ni/Ta/TaN | Silicon* | SERIES | 50 µm | 50 µm | 1000µm | 37 | \$5.95 each |
| Ta50-37-20Si | Ni/Ta/TaN | Silicon* | PARALLEL | 50 µm | 50 µm | 3700µm | 20 | \$5.95 each |
| Ta20-37-40Si | Ni/Ta/TaN | Silicon* | PARALLEL | 20 µm | 20 µm | 3700µm | 40 | \$5.95 each |
| Ta10-37-100Si | Ni/Ta/TaN | Silicon* | PARALLEL | 10 µm | 10 µm | 3700µm | 100 | \$5.95 each |
| | | | | | | | | |
| MODEL # | METAL MATERIAL | SUBSTRATE MATERIAL | ТҮРЕ | WIDTH | SPACE | LENGTH | NUMBER OF ELEMENTS | PRICE EACH |
| MODEL # Ta50-10-37G | METAL MATERIAL Ni/Ta/TaN | SUBSTRATE MATERIAL Glass | TYPE SERIES | WIDTH 50 μm | SPACE 50 μm | LENGTH 1000µm | NUMBER OF ELEMENTS 37 | PRICE EACH \$9.95 each |
| MODEL # Ta50-10-37G Ta50-37-20G | METAL MATERIAL Ni/Ta/TaN Ni/Ta/TaN | SUBSTRATE MATERIAL Glass Glass | TYPE SERIES PARALLEL | WIDTH 50 μm 50 μm | SPACE 50 μm 50 μm | LENGTH 1000μm 3700μm | NUMBER OF ELEMENTS 37 20 | PRICE EACH \$9.95 each \$9.95 each |
| MODEL # Ta50-10-37G Ta50-37-20G Ta20-37-40G | METAL MATERIAL Ni/Ta/TaN Ni/Ta/TaN Ni/Ta/TaN | SUBSTRATE MATERIAL Glass Glass Glass | TYPE SERIES PARALLEL PARALLEL | WIDTH 50 μm 50 μm 20 μm | SPACE 50 μm 50 μm 20 μm | LENGTH 1000μm 3700μm 3700μm | NUMBER OF ELEMENTS 37 20 40 | PRICE EACH \$9.95 each \$9.95 each \$9.95 each |

Dr. Lynn F. Fuller, Professor Electrical and Microelectronic Engineering Rochester Institute of Technology 82 Lomb Memorial Drive Rochester, NY 14623-5604 Email: Lynn.Fuller@rit.edu Dr. Fuller's Webpage: http://people.rit.edu/Iffeee



Silicon* is 6500Å oxide on silicon Size 4.8 mm x 4.8 mm x 0.67 mm Solder Pads for Interconnect Other metals available

© August 27, 2010 Dr. Lynn Fuller

RIT Chemical Sensors RIT ELECTRODE ARRAYS П © August 27, 2010 Dr. Lynn Fuller Page 30

